## NSN 5961-01-080-8162

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-080-8162 **Inclosure Material:** Ceramic **Overall Length:** 0.160 inches **Overall Width:** 0.500 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter **Current Rating Per Characteristic:** 12.00 amperes source cutoff current **Power Rating Per Characteristic:** 140.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 4 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No